

Vishay Semiconductors

Small Signal Fast Switching Diode

Features

- · Silicon Epitaxial Planar Diodes
- Electrical data identical with the device 1N4154
- MicroMELF package
- · AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition









Applications

· Extreme fast switches

Mechanical Data

Case: MicroMELF
Weight: approx. 12 mg
Cathode band color: black
Packaging codes/options:

TR3 / 10 k per 13" reel (8 mm tape), 10 k/box TR / 2.5 k per 7" reel (8 mm tape), 12.5 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks	
MCL4154 V _{RRM} = 35 V		MCL4154-TR3 or MCL4154-TR	Tape and Reel	

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Repetitive peak reverse voltage		V _{RRM}	35	V
Reverse voltage		V _R	25	V
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α
Repetitive peak forward current		I _{FRM}	450	mA
Forward continuous current		I _F	200	mA
Average forward current	V _R = 0	I _{FAV}	150	mA
Power dissipation		P _{tot}	500	mW

Vishay Semiconductors



Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction to ambient air	Mounted on epoxy-glass hard tissue, Fig. 4, 35 μm copper clad, 0.9 mm ² copper area per electrode	R_{thJA}	500	K/W
Junction temperature		T_j	175	°C
Storage temperature range		T _{stg}	- 65 to + 175	°C

Electrical Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	I _F = 30 mA	V_{F}			1000	mV
Reverse current	V _R = 25 V	I _R			100	nA
neverse current	V _R = 25 V, T _j = 150 °C	I _R			100	μΑ
Breakdown voltage	$I_R = 5 \mu A$, $t_p/T = 0.01$, $t_p = 0.3 \text{ ms}$	V _(BR)	35			V
Diode capacitance	$V_R = 0$, $f = 1$ MHz, $V_{HF} = 50$ mV	C _D			4	pF
Reverse recovery time	$I_F = I_R = 10 \text{ mA}, i_R = 1 \text{ mA}$	t _{rr}			4	ns
	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $I_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			2	ns

Typical Characteristics

T_{amb} = 25 °C, unless otherwise specified

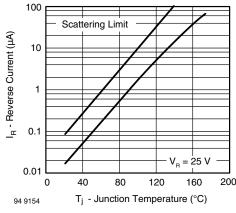


Figure 1. Reverse Current vs. Junction Temperature

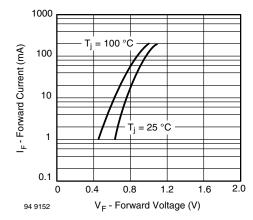


Figure 2. Forward Current vs. Forward Voltage



Vishay Semiconductors

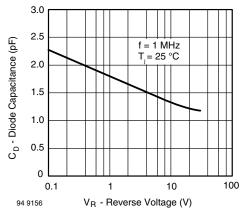


Figure 3. Diode Capacitance vs. Reverse Voltage

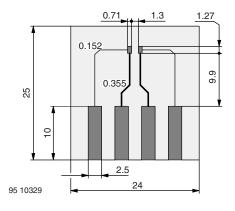
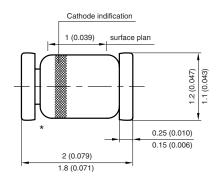
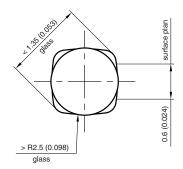


Figure 4. Board for R_{thJA} definition (in mm)

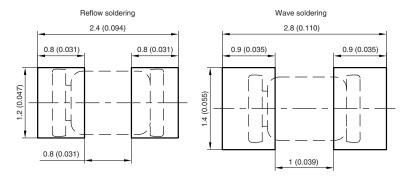
Package Dimensions in millimeters (inches): MicroMELF







Foot print recommendation:



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